

Trans GP BJT NPN 50V 8A 1000mW 3-Pin(3+Tab) TP Bag

Manufacturers	<a href="#">ON Semiconductor, LLC</a>
Package/Case	TO-251
Product Type	Transistors
RoHS	Pb-free
Lifecycle	



Images are for reference only

Please submit RFQ for 2SC5707-E or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

2SC5707 is a Bipolar Transistor, 50V, 8A, Low VCE(sat), (PNP)NPN Single TP/TP-FA for High-Current Switching Application.

## Features

- Adoption of FBET and MBIT processes
- Large current capacitance
- Low collector-to-emitter saturation voltage
- High-speed switching
- High allowable power dissipation

## Application

ONSEMI

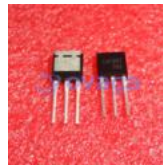


## Related Products



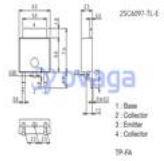
### [2SC4027S-TL-E](#)

ON Semiconductor, LLC  
TO-252



### [2SC4135T-E](#)

ON Semiconductor, LLC  
TO-251



### [2SC6097-TL-E](#)

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### [2SD1815S-TL-E](#)

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### [2SC5964-TD-E](#)

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### [2SC3648S-TD-E](#)

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### [2SA2125-TD-E](#)

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### [2SA2016-TD-E](#)

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